NPN General - Purpose Amplifier

2N3904

TO−92 3
CASE 135AN

TO−92 3
LEADFORMED
CASE 135AR

Description

This device is designed as a general−purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.

MAXIMUM RATINGS

(Values are at T_A = 25°C unless otherwise noted.) (Note 1, Note 2)

Symbol	Parameter	Value	Unit
V_{CEO}	Collector − Emitter Voltage	40	V
V_{CBO}	Collector − Base Voltage	60	V
V_{EBO}	Emitter − Base Voltage	6.0	V
I_C	Collector Current − Continuous	200	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	−55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

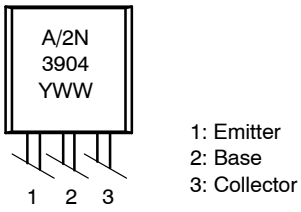
1. These ratings are based on a maximum junction temperature of 150°C.
2. These are steady−state limits. **onsemi** should be consulted on applications involving pulsed orlow−duty cycle operations.

THERMAL CHARACTERISTICS

(Values are at T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Max	Unit
P_D	Total Device Dissipation	625	mW
	Derate Above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

MARKING DIAGRAM



A = Assembly Code
2N3904 = Device Code
YWW = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

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ELECTRICAL CHARACTERISTICS (Values are at T_A = 25°C unless otherwise noted.)

Symbol	Parametr	Conditions	Min	Max	Unit
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector – Emitter Breakdown Voltage	I_C = 1.0 mA, I_B = 0	40	–	V
$V_{(BR)CBO}$	Collector – Base Breakdown Voltage	I_C = 10 μA, I_E = 0	60	–	V
$V_{(BR)EBO}$	Emitter – Base Breakdown Voltage	I_E = 10 μA, I_C = 0	6.0	–	V
I_{BL}	Base Cutoff Current	V_{CE} = 30 V, V_{EB} = 3 V	–	50	nA
I_{CEX}	Collector Cut–Off Current	V_{CE} = 30 V, V_{EB} = 3 V	–	50	nA
ON CHARACTERISTICS (Note 3)					
h_{FE}	DC Current Gain	I_C = 0.1 mA, V_{CE} = 1.0 V	40	–	–
		I_C = 1.0 mA, V_{CE} = 1.0 V	70	–	
		I_C = 10 mA, V_{CE} = 1.0 V	100	300	
		I_C = 50 mA, V_{CE} = 1.0 V	60	–	
		I_C = 100 mA, V_{CE} = 1.0 V	30	–	
$V_{CE(sat)}$	Collector – Emitter Saturation Voltage	I_C = 10 mA, I_B = 1.0 mA	–	0.2	V
		I_C = 50.0 mA, I_B = 5.0 mA	–	0.3	
$V_{BE(sat)}$	Base – Emitter Saturation Voltage	I_C = 10.0 mA, I_B = 1.0 mA	0.65	0.85	V
		I_C = 50.0 mA, I_B = 5.0 mA	–	0.95	
SMALL– SIGNAL CHARACTERISTICS					
f_T	Current – Gain – Bandwidth Product	I_C = 10 mA, V_{CE} = 20 V, f = 100 MHz	300	–	MHz
C_{obo}	Output Capacitance	V_{CB} = 5.0 V, I_E = 0, f = 100 kHz	–	4.0	pF
C_{ibo}	Input Capacitance	V_{EB} = 0.5 V, I_C = 0, f = 100 kHz	–	8.0	pF
NF	Noise Figure	I_C = 100 μA, V_{CE} = 5.0 V, R_S = 1.0 kΩ, f = 10 Hz to 15.7 kHz	–	5.0	dB
SWITCHING CHARACTERISTICS					
t_d	Delay Time	V_{CC} = 3.0 V, V_{BE} = 0.5 V, I_C = 10 mA, I_{B1} = 1.0 mA	–	35	ns
t_r	Rise Time		–	35	ns
t_s	Storage Time	V_{CC} = 3.0 V, I_C = 10 mA, I_{B1} = I_{B2} = 1.0 mA	–	200	ns
t_f	Fall Time		–	50	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width ≤ 300 μs; Duty Cycle ≤ 2%.

TYPICAL PERFORMANCE CHARACTERISTICS

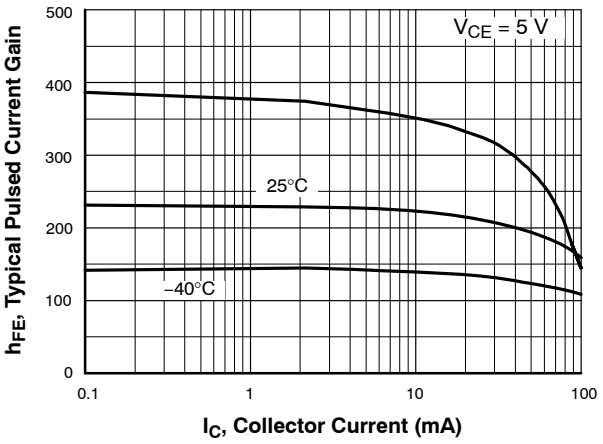

Figure 1. Typical Pulsed Current Gain vs. Collector Current

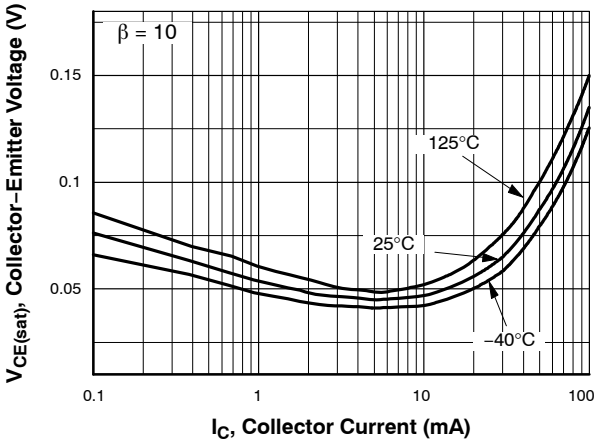

Figure 2. Collector−Emitter Saturation Voltage vs. Collector Current

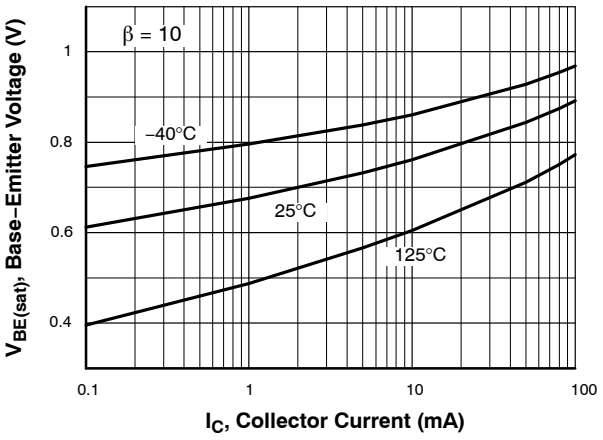

Figure 3. Base−Emitter Saturation Voltage vs. Collector Current

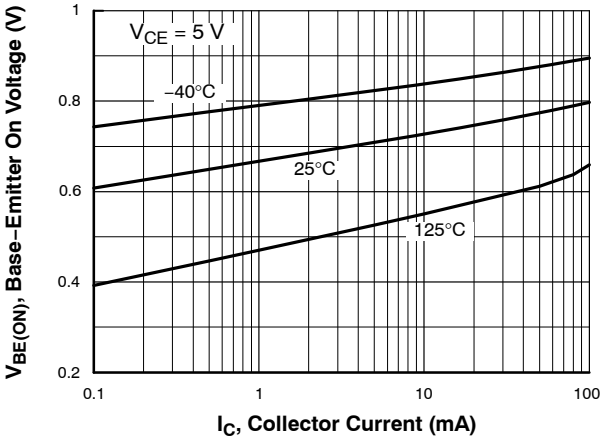

Figure 4. Base−Emitter On Voltage vs. Collector Current

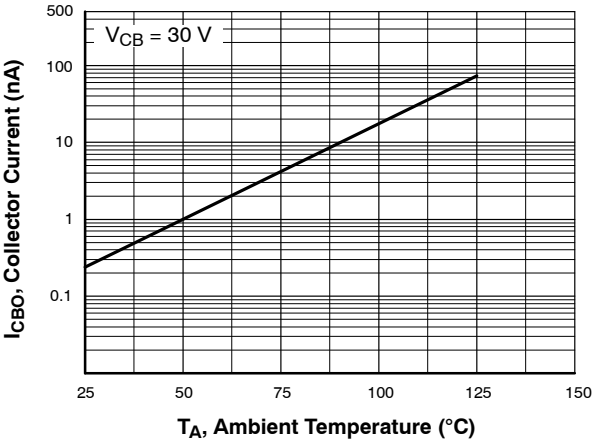

Figure 5. Collector Cut−Off Current vs. Ambient Temperature

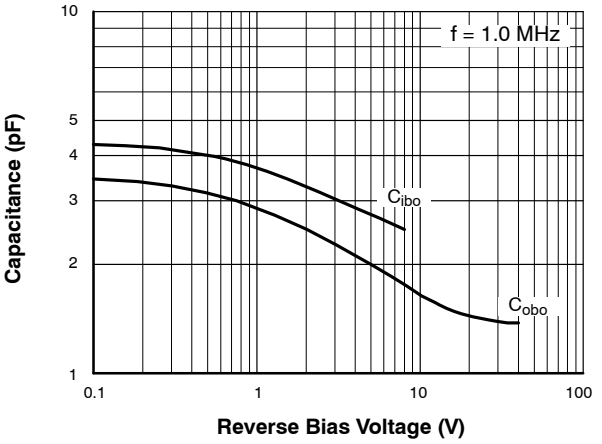

Figure 6. Capacitance vs. Reverse Bias Voltage

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

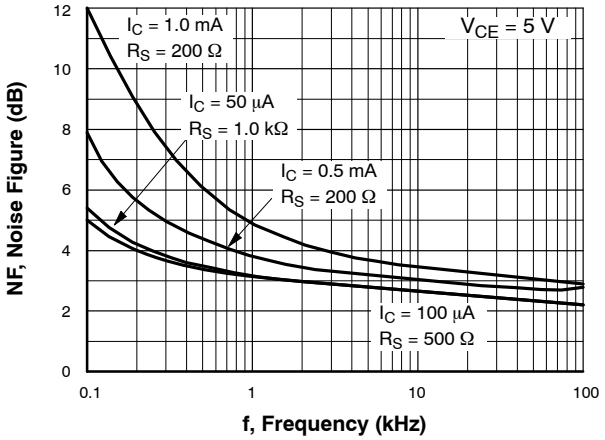

Figure 7. Noise Figure vs. Frequency

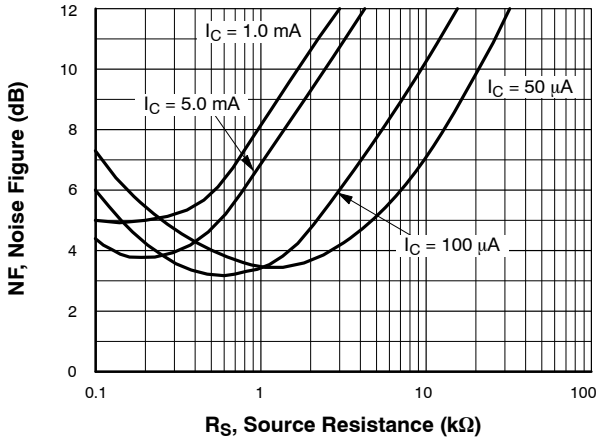

Figure 8. Noise Figure vs. Source Resistance

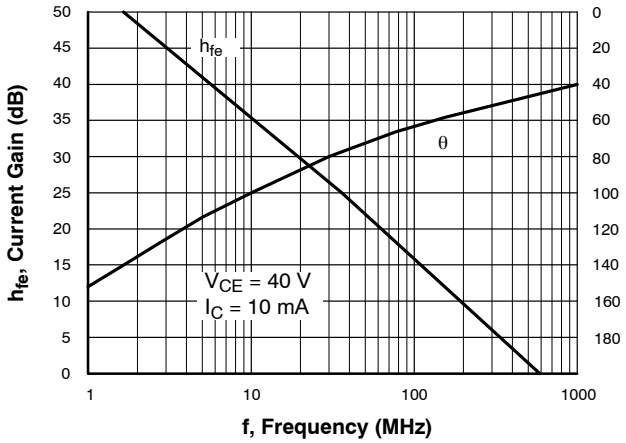

Figure 9. Current Gain and Phase Angle vs. Frequency

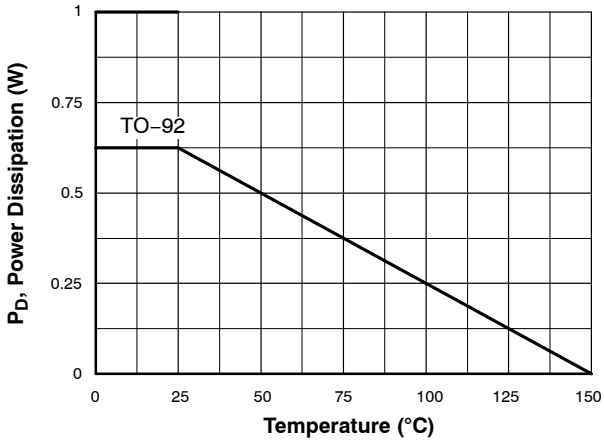

Figure 10. Power Dissipation vs. Ambient Temperature

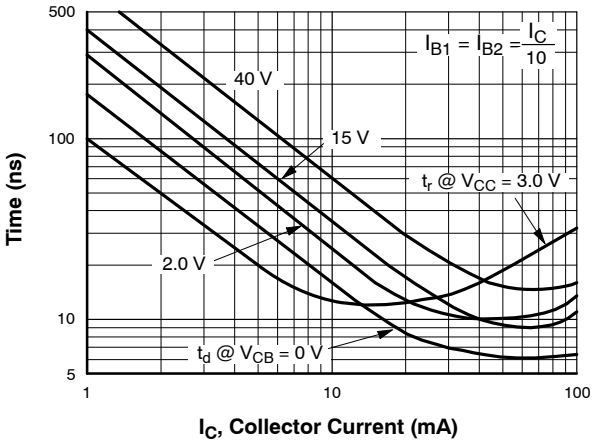

Figure 11. Turn−On Time vs. Collector Current

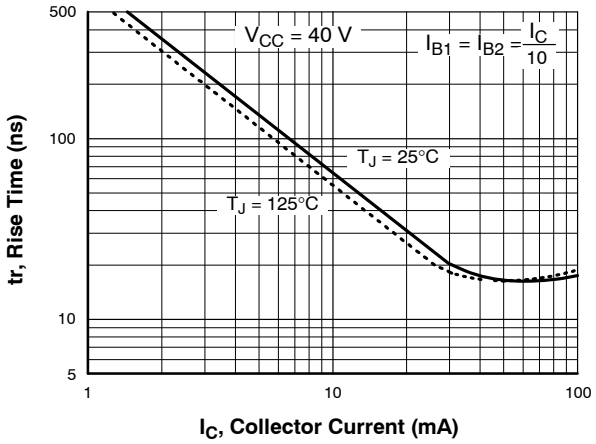

Figure 12. Rise Time vs. Collector Current

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

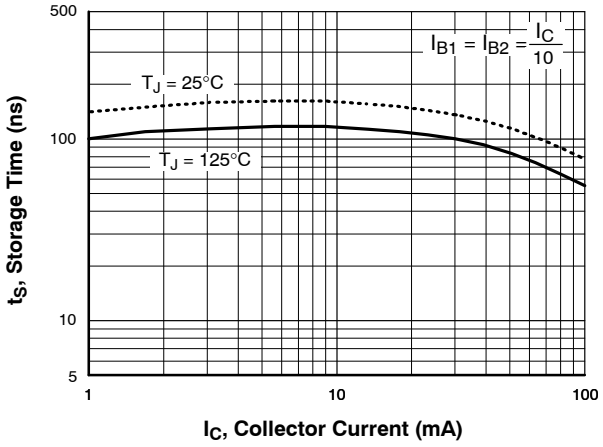

Figure 13. Storage Time vs. Collector Current

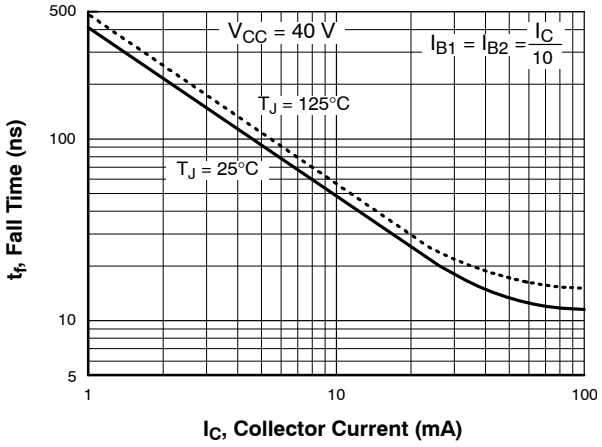

Figure 14. Fall Time vs. Collector Current

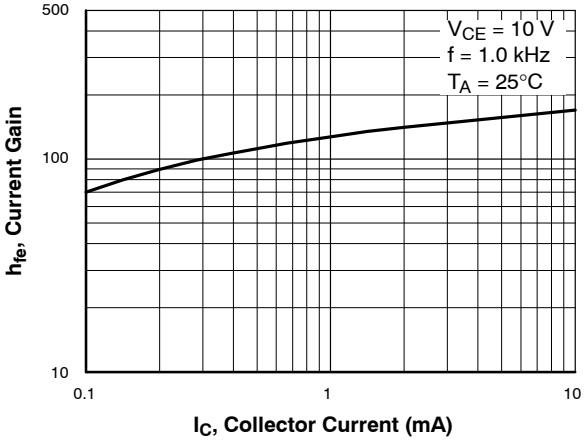

Figure 15. Current Gain

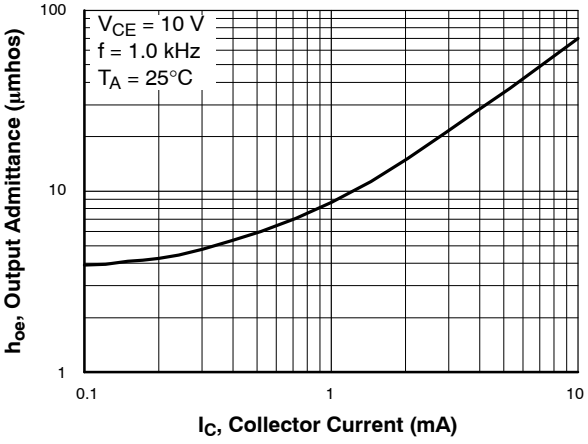

Figure 16. Output Admittance

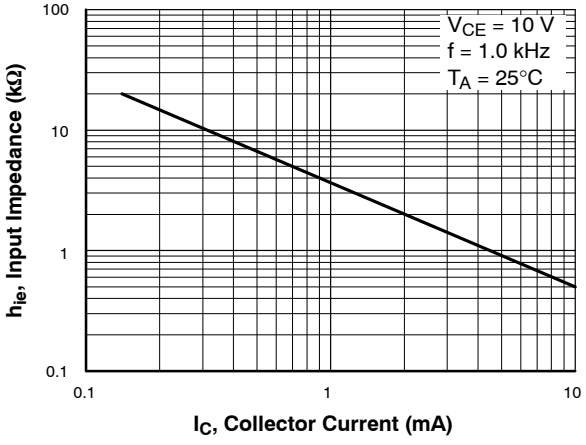

Figure 17. Input Impedance

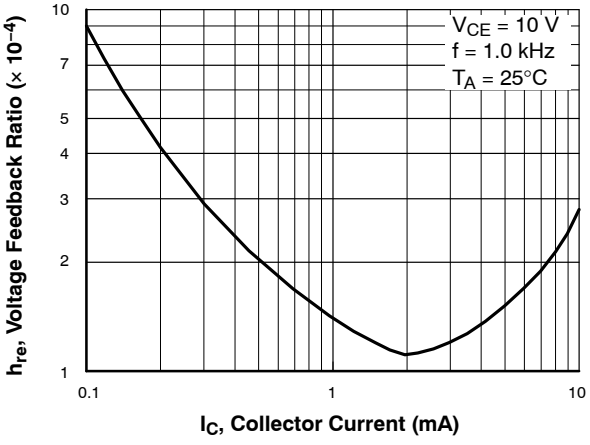

Figure 18. Voltage Feedback Ratio

TEST CIRCUITS

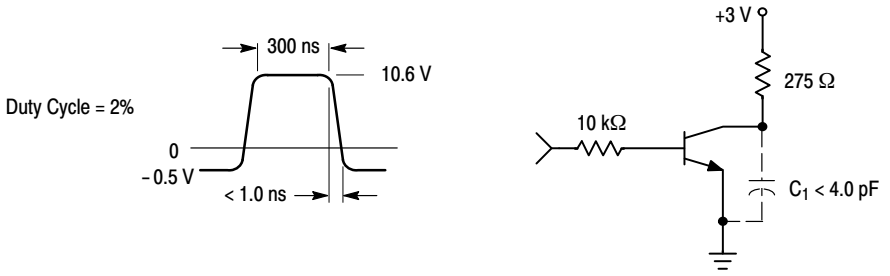

Figure 19. Delay and Rise Time Equivalent Test Circuit

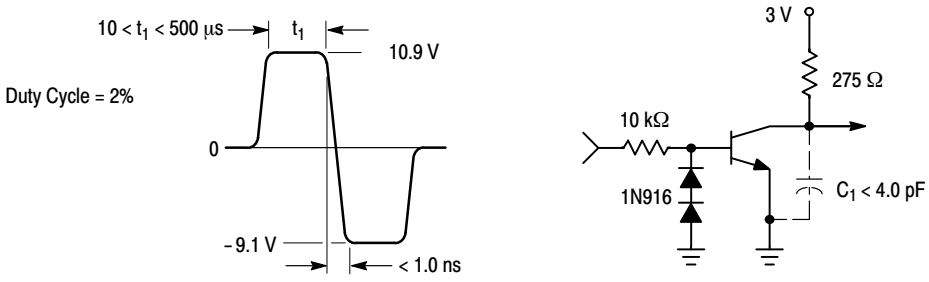

Figure 20. Storage and Fall Time Equivalent Test Circuit

ORDERING INFORMATION

Device	Package	Shipping†
2N3904BU	TO−92−3 LF (Pb−Free)	10000 Units / Bulk Bag
2N3904TA	TO−92−3 LF (Pb−Free)	2000 Units / Fan−Fold
2N3904TAR	TO−92−3 LF (Pb−Free)	2000 Units / Fan−Fold
2N3904TF	TO−92−3 LF (Pb−Free)	2000 Units / Tape & Reel
2N3904TFR	TO−92−3 LF (Pb−Free)	2000 Units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TO−92 3 4.825x4.76
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ISSUE O

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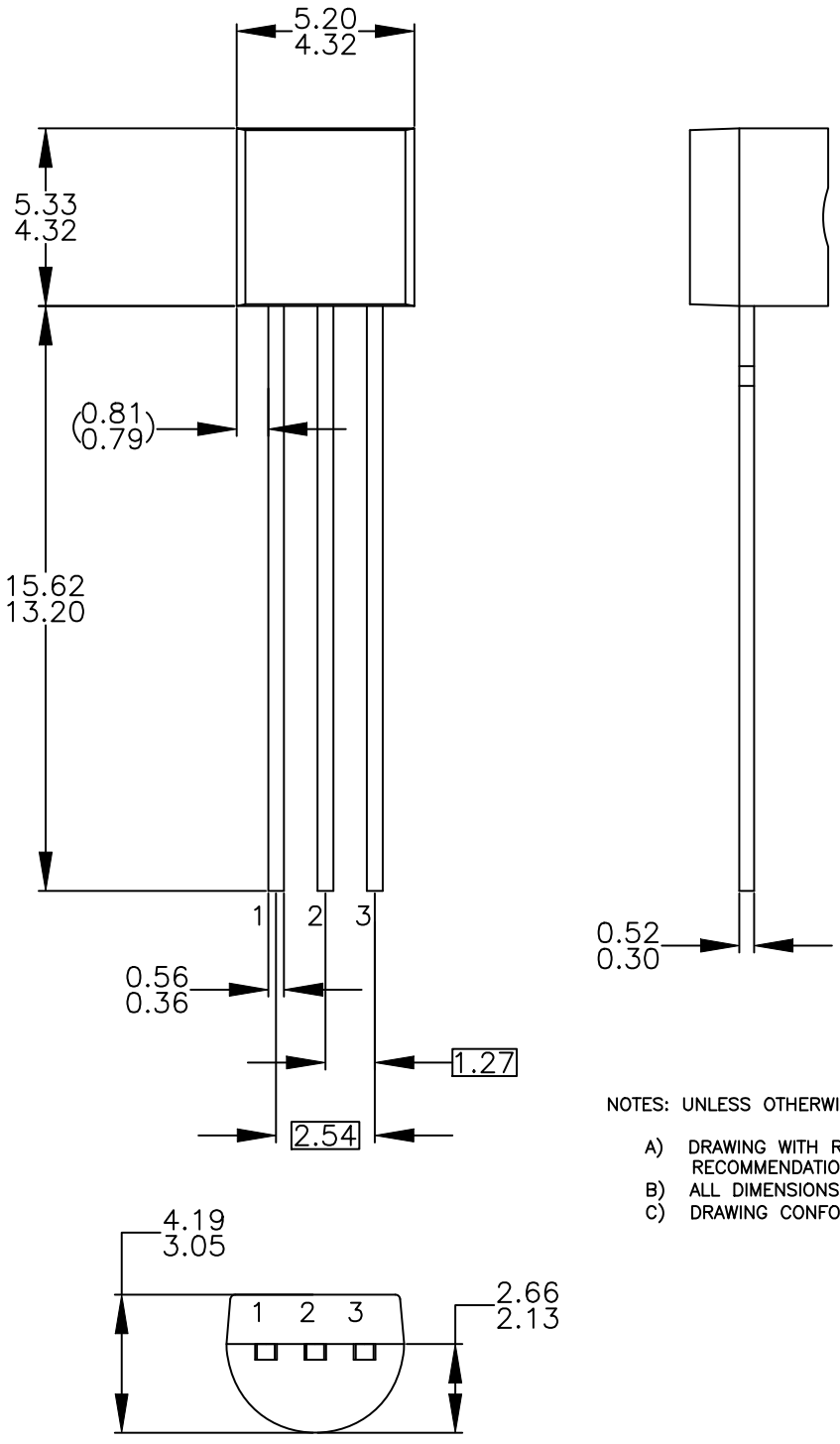

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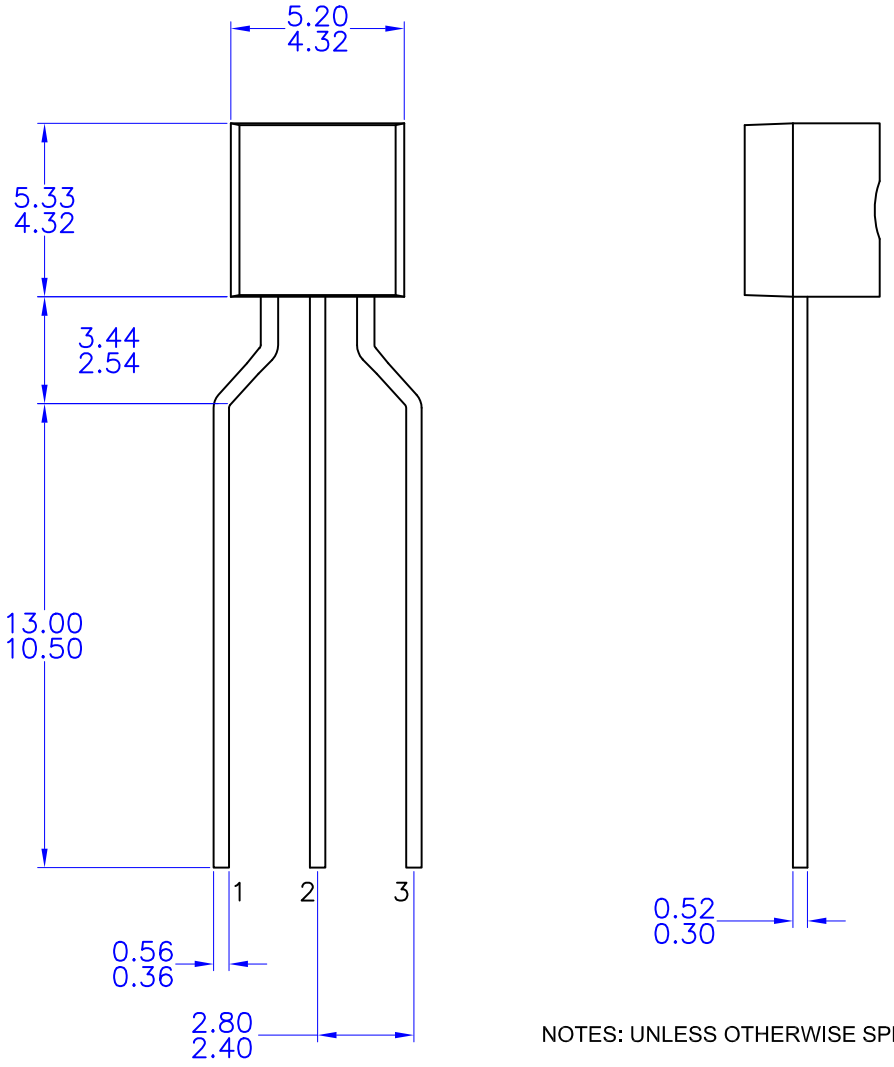

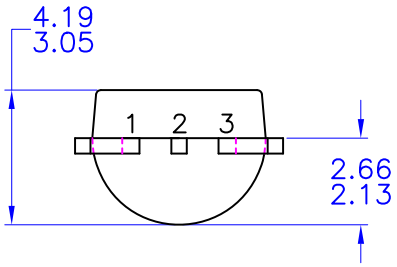

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